

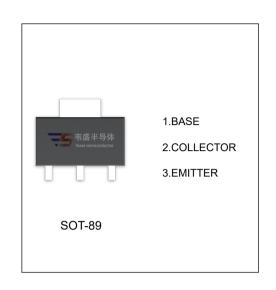
# 2SD1766 TRANSISTOR (NPN)

### **FEATURES**

- Low  $V_{CE(sat)}$ . $V_{CE(sat)}$ =0.16 $V(Typ.)(I_C/I_B$ =2A/0.2A)
- Complements to 2SB1188

## MAXIMUM RATINGS (T =<sub>a</sub>25℃ unless otherwise noted)

|                                  | , -  |         |      |  |
|----------------------------------|--|---------|------|--|
| Symbol                           | Parameter  | Value   | Unit |  |
| V <sub>CBO</sub>                 | Collector-Base Voltage                           | 40      | V    |  |
| V <sub>CEO</sub>                 | Collector-Emitter Voltage                        | 32      | V    |  |
| V <sub>EBO</sub>                 | Emitter-Base Voltage                             | 5       | V    |  |
| Ic                               | Collector Current -Continuous                    | 2       | Α    |  |
| Pc                               | Collector dissipation                            | 500     | mW   |  |
| T <sub>J</sub> ,T <sub>stg</sub> | Operation Junction and Storage Temperature Range | -55-150 | °C   |  |



# ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

| Parameter                            | Symbol               | Test conditions                                     | Min | Тур | Max | Unit |
|--------------------------------------|----------------------|---|-----|-----|-----|------|
| Collector-base breakdown voltage     | V <sub>(BR)CBO</sub> | I <sub>C</sub> =50μA, I <sub>E</sub> =0             | 40  |     |     | V    |
| Collector-emitter breakdown voltage  | V <sub>(BR)CEO</sub> | I <sub>C</sub> =1mA, I <sub>B</sub> =0              | 32  |     |     | ٧    |
| Emitter-base breakdown voltage       | V <sub>(BR)EBO</sub> | I <sub>E</sub> =50μA, I <sub>C</sub> =0             | 5   |     |     | V    |
| Collector cut-off current            | I <sub>CBO</sub>     | V <sub>CB</sub> =20V, I <sub>E</sub> =0             |     |     | 1   | μΑ   |
| Emitter cut-off current              | I <sub>EBO</sub>     | V <sub>EB</sub> =4V, I <sub>C</sub> =0              |     |     | 1   | μΑ   |
| DC current gain                      | h <sub>FE(1)</sub>   | V <sub>CE</sub> =3V, I <sub>C</sub> =500mA          | 82  |     | 390 |      |
| Collector-emitter saturation voltage | V <sub>CE(sat)</sub> | I <sub>C</sub> =2A, I <sub>B</sub> =0.2A            |     |     | 0.8 | V    |
| Transition frequency                 | f <sub>T</sub>       | V <sub>CE</sub> =5V, I <sub>C</sub> =50mA, f=100MHz |     | 100 |     | MHz  |
| Collector output capacitance         | C <sub>ob</sub>      | V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz     |     | 30  |     | pF   |

### CLASSIFICATION OF h<sub>FE(1)</sub>

| Rank    | Р      | Q       | R       |
|---------|--------|---------|---------|
| Range   | 82-180 | 120-270 | 180-390 |
| Marking | DBP    | DBQ     | DBR     |



